

Features

- 0.8 A maximum peak output current
- Rail-to-rail output voltage
- 120ns maximum propagation delay
- Under Voltage Lock-Out protection (UVLO) with hysteresis
- Wide operating range: 10 to 30 Volts (VCC)
- Guaranteed performance over temperature
 -40°C ~ +110°C.
- MSL class 1
- Regulatory Approvals
 - UL UL1577
 - VDE EN60747-5-5
 - CQC GB4943.1-2011

Applications

- Isolated IGBT/Power MOSFET gate drive
- Industrial Inverter
- AC/Brushless DC motor drives
- Induction Heating

Description

The MPH5701 series Photocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications and inverters in power supply system. It contains an LED optically coupled to an integrated circuit with a power output stage.

The Photocoupler operational parameters are guaranteed over the temperature range from 40° C $\sim +110^{\circ}$ C

Schematic





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TURTH TABLE						
LED	V _{cc} -V _{ss} (Turn-ON, +ve going)	V_{CC} - V_{SS} (Turn-OFF, -ve going)	Vo			
Off	0V to 30V	30V to 0V	Low			
On	0V to 6.9V	5.9V to 0V	Low			
On	6.9V to 8.7V	7.5V to 5.9V	Transition			
On	8.7V to 30V	30V to 7.5V	High			

Note: A 0.1μ F bypass capacitor must be connected between Pin 4 and 6.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	Min	Max	UNIT	Note
Storage Temperature	Tstg	-55	125	°C	-
Operating Temperature	Topr	-40	110	°C	-
Output IC Junction Temperature	TJ	-	125	°C	-
Total Output Supply Voltage	(V _{CC} –V _{SS})	0	35	V	-
Average Forward Input Current	IF	-	20	mA	-
Reverse Input Voltage	VR	-	5	V	-
"High" Peak Output Current	IOH(PEAK)		0.8	А	1
"Low" Peak Output Current	IOL(PEAK)		0.8	А	1
Output Voltage	$V_{O(PEAK)}$	-0.5	Vcc	V	-
Power Dissipation	Pı	-	45	mW	-
Output IC Power Dissipation	Po	-	250	mW	-
Lead Solder Temperature	Tsol	-	260	°C	-

Note: Ambient temperature = 25°C, unless otherwise specified. Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Note 1: Exponential waveform. Pulse width \leq 10 µs, f \leq 15 kHz

RECOMMENDED OPERATION CONDITIONS					
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	
Operating Temperature	T _A	-40	110	°C	
Supply Voltage	Vcc	10	30	V	
Input Current(ON)	I _{F(ON)}	7	16	mA	
Input Voltage(OFF)	V _{F(OFF)}	-3.0	0.8	V	



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ELECTRICAL OPTICAL CHARACTERISTICS							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
	INP	UT CHAF	RACTEF	RISTICS	5		
Forward Voltage	VF	1.6	2.0	2.4	V	I _F =10mA	
Input Forward Voltage Temperature Coefficient	$\Delta V_F / \Delta T$	-	-1.237	-	mV/° C	I⊧=10mA	
Input Reverse Voltage	BV _R	5	-	-	V	Ι _R =10μΑ	
Input Threshold Current (Low to High)	I _{FLH}	-	1.0	5	mA	V ₀ >5V,I ₀ =0A	
Input Threshold Voltage (High to Low)	V _{FHL}	0.8	-	-	V	V _{CC} =30V,V _O <5V	
Input Capacitance	Cin	-	60	-	pF	V _F =0, f=1kHz	
	OUT	PUT CHA	ARACTE	RISTIC	cs		
High Level Supply Current	Іссн	-	2	3	mA	I _F =10mA,V _{CC} =30V V₀=Open	
Low Level Supply Current	IccL	-	2.6	3.5	mA	I _F =0mA,V _{CC} =30V V₀=Open	
High Level Output Voltage	V _{он}	Vcc-1.0v	29.69	-	V	I⊧=10mA,I₀=-100mA	2,3
Low Level Output Voltage	V _{OL}	-	0.25	1	V	l _F =0mA,l _O =100mA	
High Level Output Current	I _{OH}		-	-0.8	Α	I _F =10mA,V _{CC} =30V V₀=V _{CC} -6	1
Low Level Output Current	I _{OL}	0.8	-	-	A	I _F =0mA,V _{CC} =30V V₀=V _{SS} +6	1
Under Voltage	VUVLO+	6.9	7.9	8.7	V	V ₀ >5V,I _F =10m	
Lockout Threshold	VUVLO-	5.9	6.8	7.5	V	V ₀ <5V,I _F =10mA	

All Typical values at $T_A = 25^{\circ}C$ and $V_{CC} - V_{SS} = 30 \text{ V}$, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Note 1: Maximum pulse width = 10 μ s.

Note 2: In this test V_{OH} is measured with a dc load current. When driving capacitive loads, V_{OH} will approach V_{CC} as I_{OH} approaches zero amps.

Note 3: Maximum pulse width = 1 ms.



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SWITCHING SPECIFICATION							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
	SWITC	HING	CHARA	CTERIS	STICS		
Propagation Delay Time to Output Low Level	t _{PHL}	-	60	120	ns		
Propagation Delay Time to Output High Level	t _{PLH}	-	55	120	ns	Rg=47Ω, Cg=3pE	
Pulse Width Distortion	PWD	-	5	80	ns	f=10kHz,	
Propagation Delay Difference Between Any Two Parts	PDD (t _{PHL} -t _{PLH})	-100	-	+100	ns	Duty Cycle=50%, I _F =10mA, Voe=30V	
Rise Time	tr	-	6	-	ns	V CC-30 V	
Fall Time	t _f	-	5	-	ns		
Common Mode Transient Immunity at Logic High	СМн	10		-	kV/µs	I _F =7 to16mA, V _{CC} =30V,T _A =25°C, V _{CM} =1.5kV	1,2
Common Mode Transient Immunity at Logic Low	CM∟	10		-	kV/µs	I _F =0mA,V _{CC} =30V, T _A =25° C,V _{CM} =1.5kV	1,3

All Typical values at $T_A = 25^{\circ}$ C and $V_{CC} - V_{SS} = 30$ V, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Note 1: Pin 2 needs to be connected to LED common.

Note 2: Common mode transient immunity in the high state is the maximum tolerable dVCM/dt of the common mode pulse, VCM, to assure that the output will remain in the high state (meaning $V_0 > 10.0V$).

Note 3: Common mode transient immunity in a low state is the maximum tolerable dVCM/dt of the common mode pulse, VCM, to assure that the output will remain in a low state (meaning $V_0 < 1.0V$).

ISOLATION CHARACTERISTIC							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
Withstand Insulation Test Voltage	V _{ISO}	5000	-	-	V	RH≪40~60%, t=1min,T _A =25°C	1,2
Input-Output Resistance	R _{I-O}	-	10 ¹²	-	Ω	V _{I-0} =500V DC	1

All Typical values at $_{TA}$ = 25°C and V_{CC} – V_{SS} = 30 V, unless otherwise specified; all minimum and maximum specifications are at recommended operating condition.

Note 1: Device is considered a two terminal device: pins 1, 2, 3 are shorted together and pins 4, 5, 6 are shorted together.

Note 2: According to UL1577, each photocoupler is tested by applying an insulation test voltage 6000VRMS for one second. This test is performed before the 100% production test for partial discharge.







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CHARACTERISTIC CURVES









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TAPING DIMENSIONS (Dimensions in mm unless otherwise stated)

Taping Dimensions



Dimension Symbol	D	E	F	P0	P1	P2	t	W	ĸ
P type Dimension (mm)	1.5±0.1	1.75±0.1	7.5±0.1	4.0±0.1	8.0±0.1	2.0±0.1	0.3±0.1	16.0±0.3	2.15±0.1
W type Dimension (mm)	1.5±0.1	1.75±0.1	11.5±0.1	4.0±0.1	8.0±0.1	2.0±0.1	0.3±0.1	24.0±0.3	2.52±0.1

Tape & Reel Packing Specifications











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REFLOW INFORMATION REFLOW PROFILE

IR Reflow soldering

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.



Ti	me	(S)
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	Symbol	Min.	Max.	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	S
Ramp-up rate (T∟to T⊳)			3	°C/s
Liquidus temperature	T∟	21	7	°C
Time above T∟	t∟	60	100	S
Peak Temperature	TΡ		260	°C
Time during which T_C is between (T_P - 5) and T_P	te		20	S
Ramp-down rate			6	°C/s



MPH-314 Series 1.0A, Gate Driver Photo Coupler

DISCLAIMER

- Our company is continually improving the quality, reliability, function and design. Our company reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Immerge unit's body in solder paste is not recommended.
- Discoloration might be occurred on the package surface after soldering, reflow or longtime use. It neither impacts the performance nor reliability.

Revision History

Version	Date	Subjects (major changes since last revision)				
1.0	2022-07-22	Datasheet Complete				